

HIGH-FREQUENCY LOW NOISE AMPLIFIER

NPN SILICON EPITAXIAL TRANSISTOR

(WITH BUILT-IN 2 $\times$ 2SC4228) SMALL MINI MOLD

The μ PA811T has built-in 2 low-voltage transistors which are designed to amplify low noise in the VHF band to the UHF band.

FEATURES

- Low Noise
NF = 1.9 dB TYP. @ f = 2 GHz, $V_{CE} = 1$ V, $I_C = 3$ mA
- High Gain
 $|S_{21e}|^2 = 6.5$ dB TYP. @ f = 2 GHz, $V_{CE} = 1$ V, $I_C = 3$ mA
- A Small Mini Mold Package Adopted
- Built-in 2 Transistors (2 $\times$ 2SC4228)

ORDERING INFORMATION

PART NUMBER	QUANTITY	PACKING STYLE
μ PA811T	Loose products (50 PCS)	Embossed tape 8 mm wide. Pin 6 (Q1 Base), Pin 5 (Q1 Emitter), Pin 4 (Q2 Emitter) face to perforation side of the tape.
μ PA811T-T1	Taping products (3 KPCS/Reel)	

Remark If you require an evaluation sample, please contact an NEC Sales Representative. (Unit sample quantity is 50 pcs.)

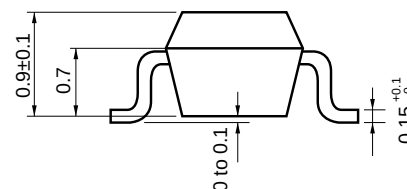
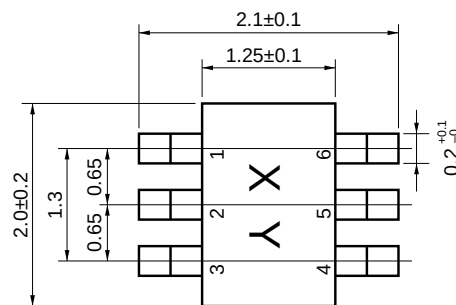
ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

PARAMETER	SYMBOL	RATING	UNIT
Collector to Base Voltage	V_{CBO}	20	V
Collector to Emitter Voltage	V_{CEO}	10	V
Emitter to Base Voltage	V_{EBO}	1.5	V
Collector Current	I_C	35	mA
Total Power Dissipation	P_T	150 in 1 element 200 in 2 elements ^{Note}	mW
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-65 to +150	$^\circ\text{C}$

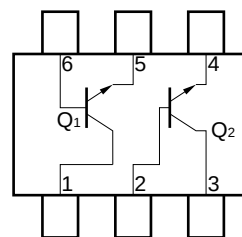
Note 110 mW must not be exceeded in 1 element.

PACKAGE DRAWINGS

(Unit: mm)



PIN CONFIGURATION (Top View)



PIN CONNECTIONS

- | | |
|-------------------|-----------------|
| 1. Collector (Q1) | 4. Emitter (Q2) |
| 2. Base (Q2) | 5. Emitter (Q1) |
| 3. Collector (Q2) | 6. Base (Q1) |

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)

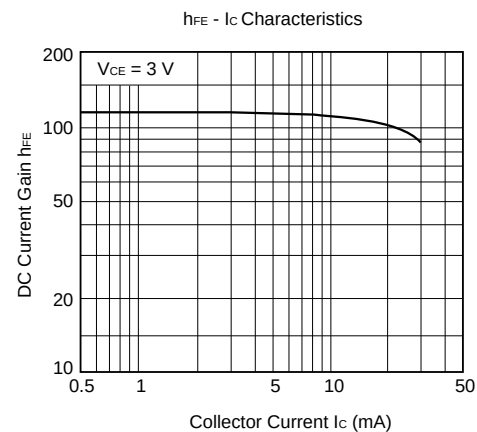
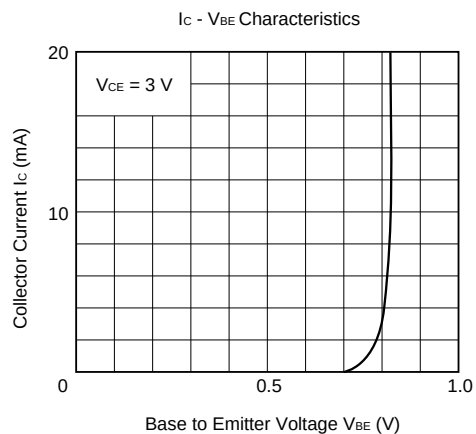
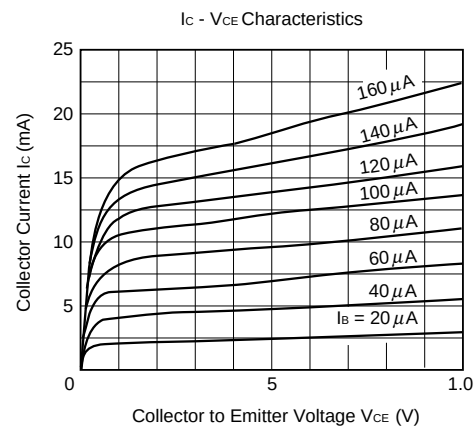
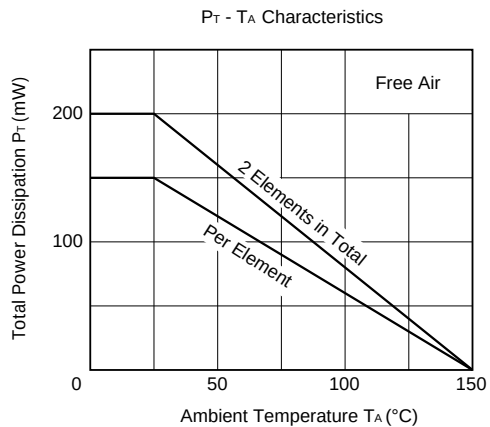
PARAMETER	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cutoff Current	I_{CBO}	$V_{CB} = 10\text{ V}, I_E = 0$			1.0	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = 1\text{ V}, I_C = 0$			1.0	μA
DC Current Gain	h_{FE}	$V_{CE} = 3\text{ V}, I_C = 5\text{ mA}$ ^{Note 1}	80		200	
Gain Bandwidth Product	f_T	$V_{CE} = 3\text{ V}, I_C = 5\text{ mA}$	5.5	8.0		GHz
Feed-back Capacitance	C_{re}	$V_{CB} = 3\text{ V}, I_E = 0, f = 1\text{ MHz}$ ^{Note 2}			0.7	pF
Insertion Power Gain	$ S_{21e} ^2$	$V_{CE} = 3\text{ V}, I_C = 5\text{ mA}, f = 2\text{ GHz}$	5.5	7.5		dB
Noise Figure	NF	$V_{CE} = 3\text{ V}, I_C = 5\text{ mA}, f = 2\text{ GHz}$		1.9	3.2	dB
h_{FE} Ratio	h_{FE1}/h_{FE2}	$V_{CE} = 3\text{ V}, I_C = 5\text{ mA}$ A smaller value among h_{FE} of $h_{FE1} = Q1, Q2$ A Larger value among h_{FE} of $h_{FE2} = Q1, Q2$	0.85			

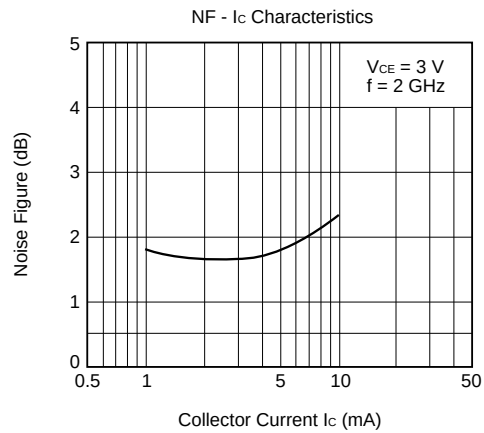
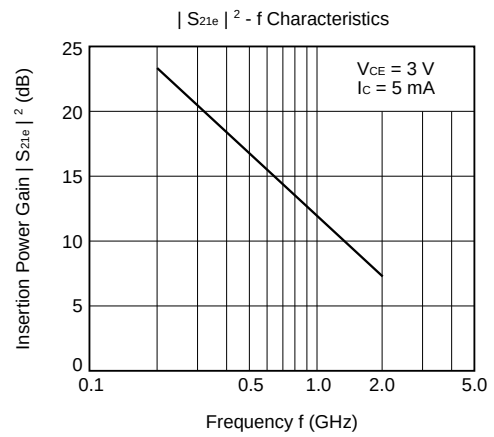
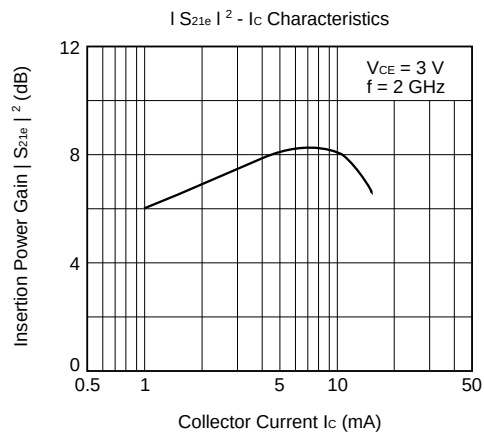
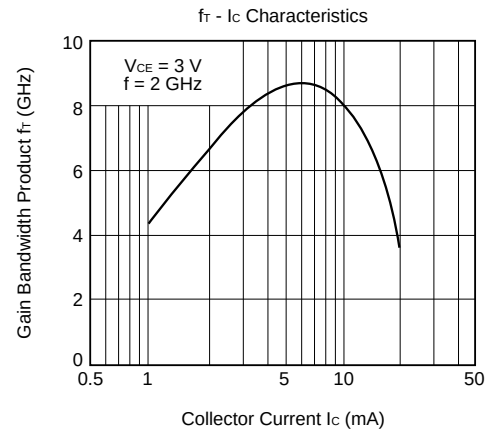
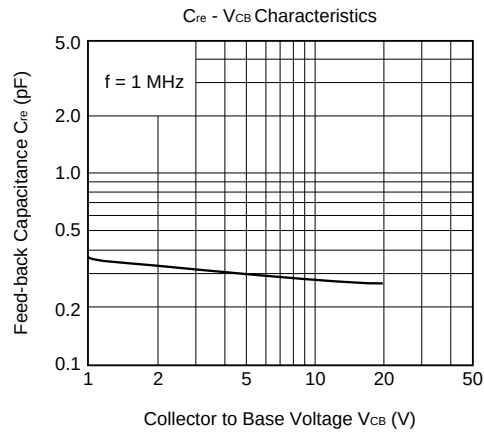
Notes 1. Pulse Measurement: $P_w \leq 350\text{ }\mu\text{s}$, Duty cycle $\leq 2\%$

2. Measured with 3-pin bridge, emitter and case should be connected to guard pin of bridge.

 h_{FE} CLASSIFICATION

Rank	FB	GB
Marking	44R	45R
h_{FE} Value	80 to 160	125 to 250

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)



S-PARAMETERS $V_{CE} = 3\text{ V}$, $I_C = 1\text{ mA}$

FREQUENCY	S ₁₁		S ₂₁		S ₁₂		S ₂₂		
	MHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100.00	0.969	-7.9	3.625	172.0	0.016	85.0	0.999	-3.6	
200.00	0.957	-14.7	3.405	165.9	0.031	80.7	0.989	-6.4	
300.00	0.909	-21.2	3.366	156.4	0.046	73.3	0.961	-10.4	
400.00	0.909	-27.4	3.218	153.3	0.059	70.9	0.955	-12.4	
500.00	0.895	-33.5	3.147	144.8	0.071	66.4	0.913	-14.2	
600.00	0.876	-42.4	3.150	141.2	0.083	65.6	0.913	-16.7	
700.00	0.821	-49.4	3.040	132.0	0.092	60.7	0.896	-18.0	
800.00	0.750	-56.0	2.966	126.2	0.105	58.0	0.888	-21.1	
900.00	0.710	-60.5	2.779	119.6	0.110	55.8	0.869	-23.3	
1000.00	0.673	-65.3	2.640	114.1	0.119	51.5	0.840	-27.3	
1100.00	0.658	-72.2	2.532	110.6	0.124	51.0	0.805	-28.9	
1200.00	0.625	-78.4	2.504	105.6	0.129	48.2	0.758	-30.8	
1300.00	0.573	-85.4	2.427	102.7	0.138	46.2	0.738	-31.1	
1400.00	0.537	-91.2	2.350	96.2	0.137	44.5	0.706	-31.5	
1500.00	0.505	-97.1	2.305	92.3	0.143	42.0	0.709	-32.1	
1600.00	0.479	-103.2	2.210	88.3	0.142	43.8	0.693	-32.6	
1700.00	0.448	-110.2	2.152	83.6	0.148	41.9	0.689	-35.3	
1800.00	0.424	-115.4	2.101	81.0	0.155	42.9	0.678	-36.5	
1900.00	0.399	-120.9	2.034	75.9	0.157	40.4	0.650	-39.1	
2000.00	0.389	-127.2	1.987	71.7	0.165	38.1	0.631	-40.5	

 $V_{CE} = 3\text{ V}$, $I_C = 3\text{ mA}$

FREQUENCY	S ₁₁		S ₂₁		S ₁₂		S ₂₂		
	MHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100.00	0.903	−14.0	8.928	165.7	0.016	89.5	0.985	−6.5	
200.00	0.856	−25.6	8.248	154.2	0.028	74.6	0.951	−11.2	
300.00	0.763	−36.2	7.535	141.5	0.042	68.0	0.889	−16.4	
400.00	0.713	−44.7	6.882	135.1	0.051	65.0	0.851	−18.6	
500.00	0.656	−52.3	6.233	125.9	0.058	61.2	0.785	−20.1	
600.00	0.602	−62.4	5.854	121.4	0.067	61.4	0.764	−21.7	
700.00	0.536	−70.5	5.342	112.1	0.072	58.8	0.733	−21.9	
800.00	0.466	−77.7	4.989	106.9	0.080	57.9	0.717	−23.8	
900.00	0.412	−82.8	4.471	100.4	0.084	58.0	0.696	−25.0	
1000.00	0.374	−87.8	4.123	95.3	0.091	55.7	0.669	−27.6	
1100.00	0.346	−93.4	3.871	92.3	0.095	56.9	0.639	−28.3	
1200.00	0.315	−100.2	3.667	88.1	0.100	55.9	0.603	−29.2	
1300.00	0.285	−106.7	3.575	86.0	0.108	55.8	0.587	−28.7	
1400.00	0.263	−112.8	3.367	81.3	0.111	55.6	0.566	−28.3	
1500.00	0.245	−119.7	3.214	78.3	0.118	54.5	0.570	−28.2	
1600.00	0.230	−126.7	3.038	75.5	0.121	57.3	0.561	−28.3	
1700.00	0.214	−135.0	2.918	72.3	0.129	55.9	0.559	−30.5	
1800.00	0.202	−141.2	2.821	69.9	0.137	57.2	0.553	−31.5	
1900.00	0.192	−147.9	2.696	65.8	0.143	54.8	0.532	−33.7	
2000.00	0.193	−154.2	2.613	61.8	0.152	53.2	0.515	−34.7	

S-PARAMETERS $V_{CE} = 3\text{ V}$, $I_C = 5\text{ mA}$

FREQUENCY	S ₁₁		S ₂₁		S ₁₂		S ₂₂	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100.00	0.848	-18.5	12.800	161.3	0.015	78.5	0.974	-8.3
200.00	0.766	-33.1	11.314	146.2	0.026	71.6	0.913	-14.0
300.00	0.647	-45.5	9.862	132.5	0.038	66.4	0.829	-19.0
400.00	0.575	-54.3	8.611	125.0	0.044	64.0	0.778	-20.4
500.00	0.506	-62.0	7.527	116.3	0.052	62.0	0.712	-20.9
600.00	0.450	-71.5	6.847	112.2	0.058	63.0	0.691	-21.5
700.00	0.393	-79.6	6.116	103.6	0.064	61.6	0.666	-21.0
800.00	0.335	-86.5	5.624	99.2	0.072	61.8	0.652	-22.2
900.00	0.290	-91.7	4.970	93.3	0.076	62.4	0.637	-23.1
1000.00	0.260	-97.0	4.521	88.7	0.084	60.4	0.616	-25.3
1100.00	0.236	-102.5	4.202	86.2	0.088	62.0	0.592	-25.7
1200.00	0.213	-109.7	3.947	82.4	0.094	61.2	0.561	-26.4
1300.00	0.193	-116.7	3.792	80.3	0.102	61.3	0.550	-25.7
1400.00	0.178	-123.3	3.468	76.1	0.106	61.1	0.532	-25.1
1500.00	0.168	-131.8	3.408	73.8	0.115	60.2	0.538	-25.1
1600.00	0.161	-139.7	3.218	71.4	0.118	62.3	0.533	-25.2
1700.00	0.153	-149.2	3.085	68.7	0.128	60.8	0.532	-27.5
1800.00	0.148	-156.1	2.980	66.4	0.137	61.9	0.527	-28.5
1900.00	0.143	-163.5	2.840	62.7	0.143	59.4	0.507	-30.7
2000.00	0.149	-169.9	2.752	58.8	0.153	57.6	0.492	-31.8

No part of this document may be copied or reproduced in any form or by any means without the prior written consent of NEC Corporation. NEC Corporation assumes no responsibility for any errors which may appear in this document.

NEC Corporation does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from use of a device described herein or any other liability arising from use of such device. No license, either express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC Corporation or others.

While NEC Corporation has been making continuous effort to enhance the reliability of its semiconductor devices, the possibility of defects cannot be eliminated entirely. To minimize risks of damage or injury to persons or property arising from a defect in an NEC semiconductor device, customer must incorporate sufficient safety measures in its design, such as redundancy, fire-containment, and anti-failure features.

NEC devices are classified into the following three quality grades:

“Standard”, “Special”, and “Specific”. The Specific quality grade applies only to devices developed based on a customer designated “quality assurance program” for a specific application. The recommended applications of a device depend on its quality grade, as indicated below. Customers must check the quality grade of each device before using it in a particular application.

Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

The quality grade of NEC devices in “Standard” unless otherwise specified in NEC's Data Sheets or Data Books. If customers intend to use NEC devices for applications other than those specified for Standard quality grade, they should contact NEC Sales Representative in advance.

Anti-radioactive design is not implemented in this product.